GTM

CORPORATION ISSUED DATE :2005/12/20 REVISED DATE :2006/05/24B

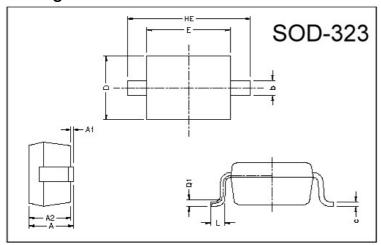
GD401SD

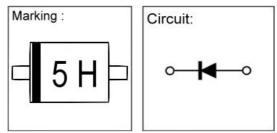
SURFACE MOUNT, SCHOTTKY BARRIER DIODE **VOLTAGE 30V, CURRENT 0.2A**

Description

The GD401SD is high frequency rectification for switching power supply.

Package Dimensions





REF.	Millimeter		REF.	Millimeter		
	Min.	Max.	r∟.	Min.	Max.	
Α	0.85	1.05				
A1	0	0.10	L	0.20	0.40	
A2	0.80	1.00	b	0.25	0.40	
D	1.15	1.45	С	0.10	0.18	
Е	1.60	1.80				
HE	2.30	2.70	Q1	0.15 BSC.		

Absolute Maximum Ratings at TA = 25℃

Parameter	Symbol	Ratings	Unit	
Junction Temperature	Tj	+125	$^{\circ}\!\mathbb{C}$	
Storage Temperature	Tstg	-55 ~ +125	$^{\circ}$ C	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	30	V	
Maximum RMS Voltage	V_{RMS}	21	V	
Maximum DC Blocking Voltage	V_{DC}	30	V	
Peak Forward Surge Current at 8.3mSec single half sine-wave	I _{FSM}	3.0	Α	
Typical Junction Capacitance between Terminal (Note 1)	CJ	40	pF	
Maximum Average Forward Rectified Current	lo	0.2	A	
Total Power Dissipation	PD	mW		

Electrical Characteristics (at TA = 25°C unless otherwise noted)

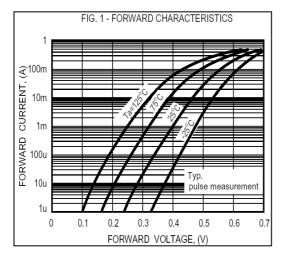
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Reverse Breakdown Voltage	V(BR)R	30	-	-	٧	IR=100μA
Maximum Instantaneous Forward Voltage	VF	-	-	500	mV	IF=200mA
Maximum Average Reverse Current	lR	1	-	50	μΑ	VR1=10V
INIAXIIIIUIII Average neverse Current	IK	-	-	100	μΑ	VR2=30V

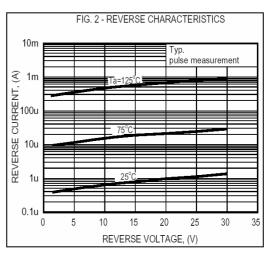
Notes: 1. Measured at 1.0 MHz and 0 reverse bias voltage.

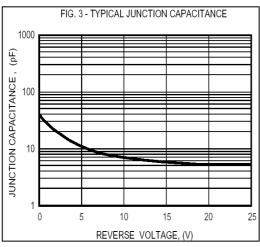
2. ESD sensitive product handling required.

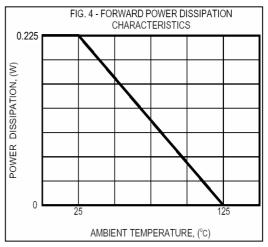
GD401SD Page: 1/2

Characteristics Curve









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GD401SD Page: 2/2